

BAV19S Diodes

General Purpose Fast Rectifier

Military/High-Rel N

I(O) Max.(A) Output Current 200m

V(RRM)(V) Rep.Pk.Rev. Voltage 120

t(rr) Max.(s) Rev.Rec. Time 50n

@I(F) (A) (Test Condition) 30m

@I(R) (A) (Test Condition) 30m

V(FM) Max.(V) Forward Voltage 1

@I(FM) (A) (Test Condition) 100m

@V(RM) (V) (Test Condition)

I(RM) Max.(A) Reverse Current 100n

@V(R) (V)(Test Condition) 100

I(RM) Max.(A) Pk. Rev. Current

@V(R) (V) (Test Condition)

@Temp. (°C) (Test Condition)

Semiconductor Material Silicon

Maximum Operating Temp (°C) 175ö

Package Style DO-34